



**THE UNITED STATES PATENT AND TRADEMARK OFFICE**

Applicant: Yasuhiro OKAMOTO et al.  
Title: FIELD-EFFECT TRANSISTOR HAVING GROUP III  
NITRIDE ELECTRODE STRUCTURE (As Amended)  
Appl. No.: 10/538,739  
Filing Date: 11/9/2005  
Examiner: Sarah Kate Salerno  
Art Unit: 2814  
Confirmation No.: 7288

**AMENDMENT AND REPLY UNDER 37 C.F.R. 1.111**

Mail Stop Amendment  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Sir:

This communication is responsive to the Non-Final Office Action dated December 28, 2007, concerning the above-referenced patent application.

A petition and fee for a one-month extension of time are being submitted concurrently herewith.

**Amendments to the Specification** begin on page 2 of this document.

**Amendments to the Claims** are reflected in the listing of claims which begins on page 3 of this document.

**Amendments to the Drawings** begin on page 8 of this document, and include attached replacement drawing sheets.

**Remarks/Arguments** begin on page 9 of this document.

Please amend the application as follows: